



IXTB30N100L Information

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For Reference Only

Part Number IXTB30N100L

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 1000V 30A PLUS264

Package TO-264-3, TO-264AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXTB30N100L Specifications

Manufacturer Part Number	IXTB30N100L
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-264-3, TO-264AA
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1000V
Current - Continuous Drain (Id) @ 25°C	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	20V
Vgs(th) (Max) @ Id	5V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	545nC @ 20V
Input Capacitance (Ciss) (Max) @ Vds	13200pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	800W (Tc)
Rds On (Max) @ Id, Vgs	450 mOhm @ 500mA, 20V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PLUS264?
Package / Case	TO-264-3, TO-264AA
	Report errors?

IXTB30N100L Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTB30N100L Payment Methods





















IXTB30N100L Shipping Methods













If you have any question about IXTB30N100L, please do not hesitate to contact us!

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